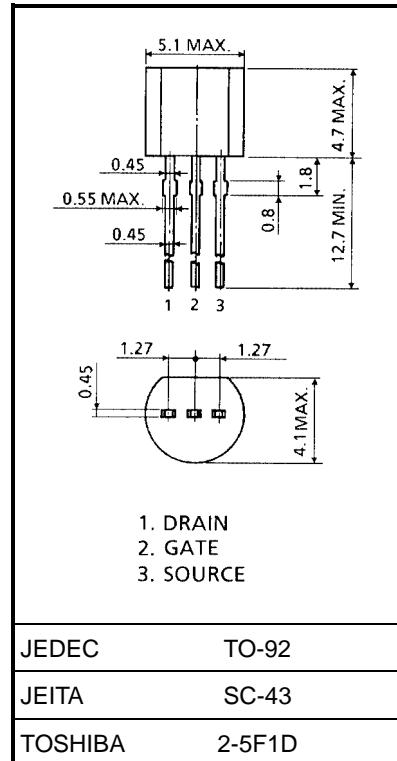


TOSHIBA Field Effect Transistor Silicon N Channel Junction Type

2SK364

For Audio Amplifier, Analog Switch, Constant Current and Impedance Converter Applications

Unit: mm



- High breakdown voltage: $V_{GDS} = -40$ V
- High input impedance: $I_{GSS} = -1.0$ nA (max) ($V_{GS} = -30$ V)
- Low R_{DS} (ON): R_{DS} (ON) = 50 Ω (typ.) ($I_{DSS} = 5$ mA)
- Complementary to 2SJ104

Maximum Ratings ($T_a = 25^\circ\text{C}$)

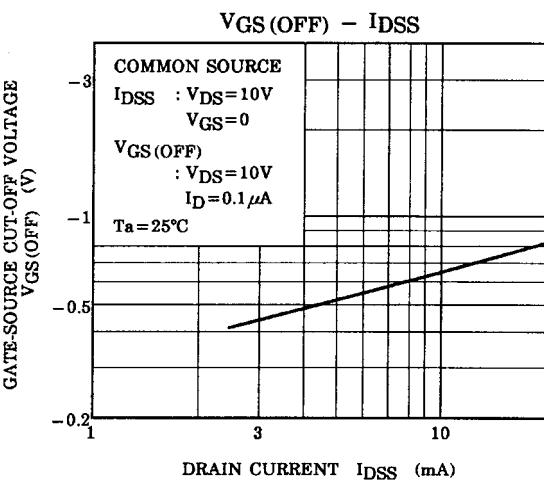
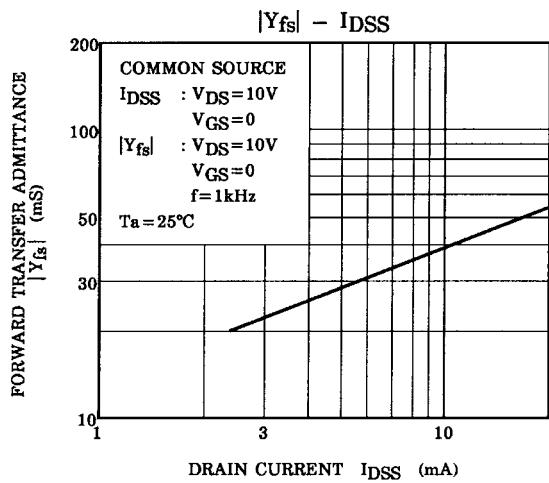
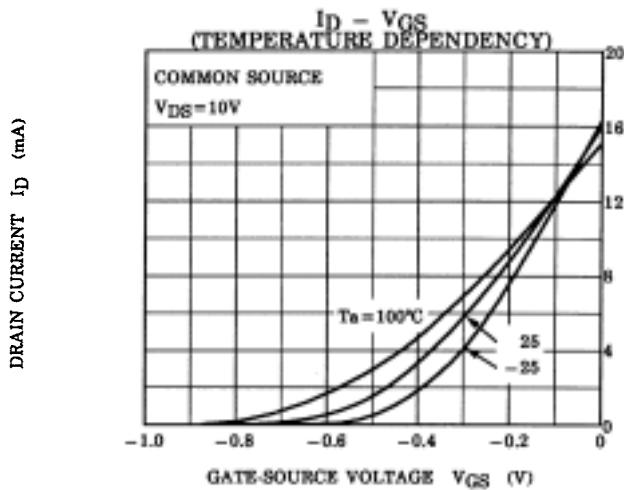
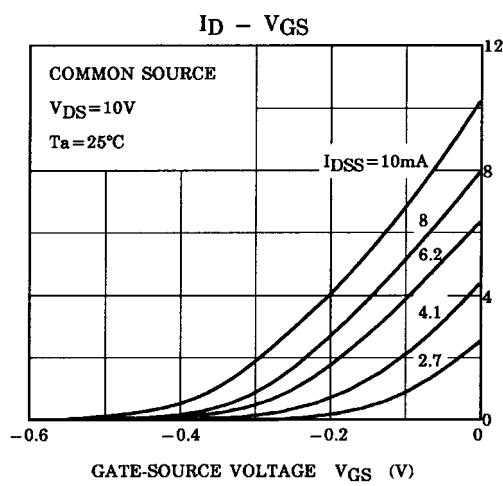
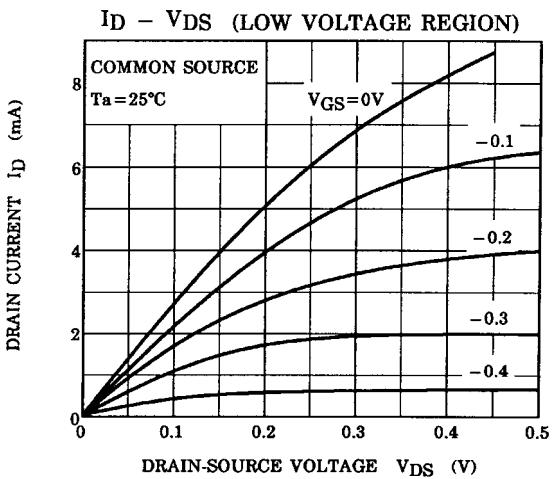
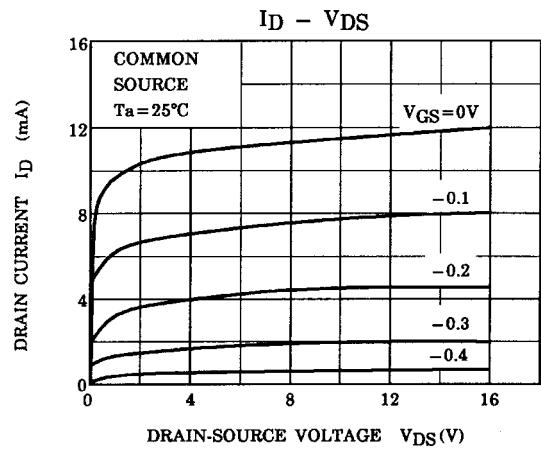
| Characteristics | Symbol | Rating | Unit |
|---------------------------|-----------|---------|------------------|
| Gate-drain voltage | V_{GDS} | -40 | V |
| Gate current | I_G | 10 | mA |
| Drain power dissipation | P_D | 400 | mW |
| Junction temperature | T_j | 125 | $^\circ\text{C}$ |
| Storage temperature range | T_{stg} | -55~125 | $^\circ\text{C}$ |

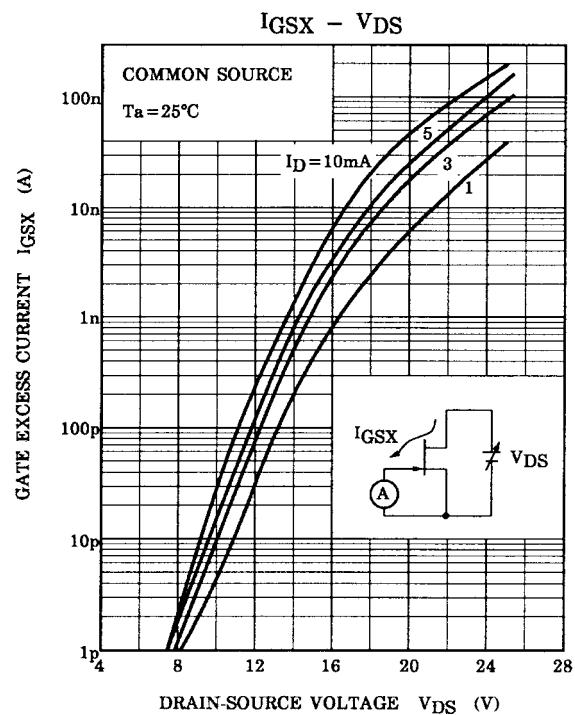
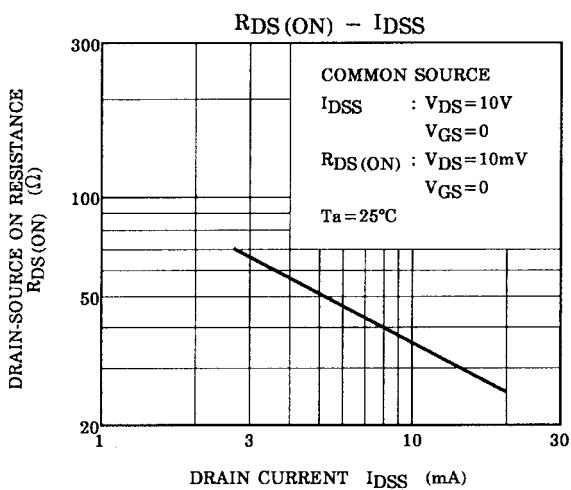
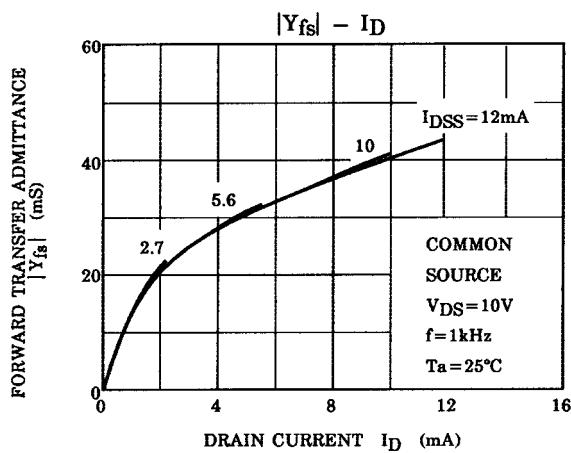
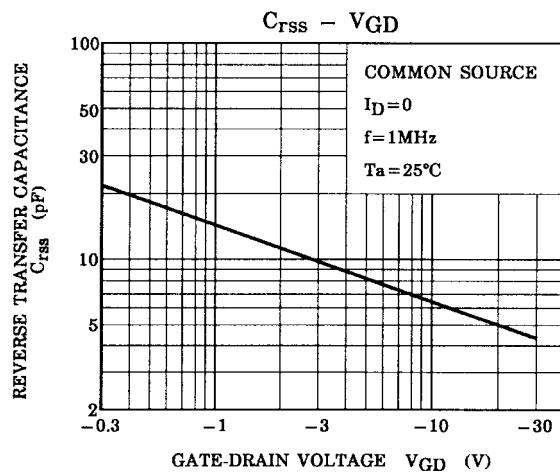
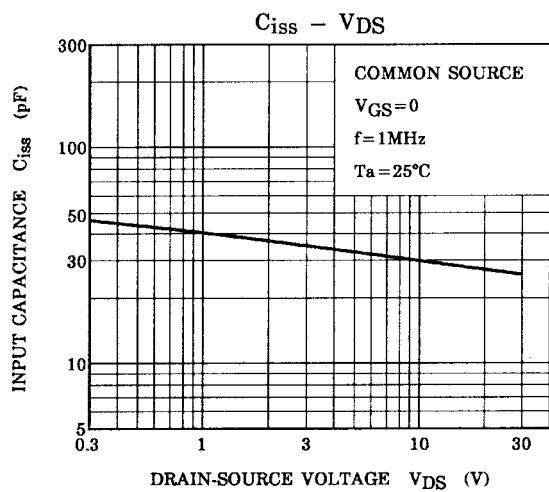
Weight: 0.21 g (typ.)

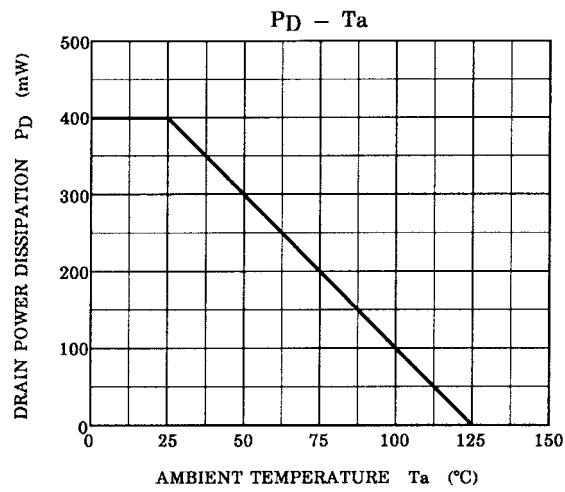
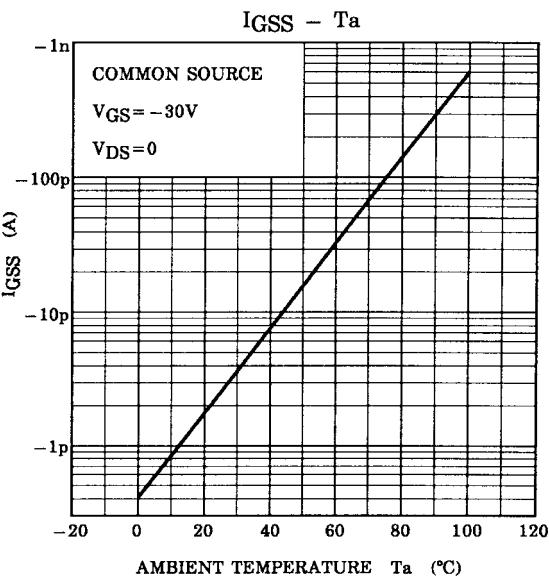
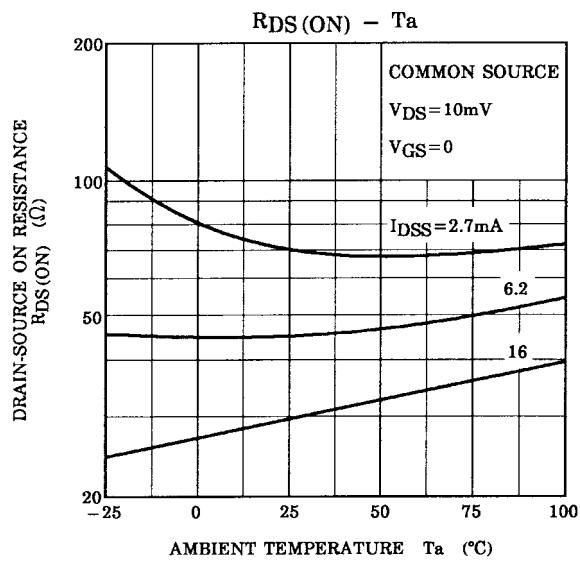
Electrical Characteristics ($T_a = 25^\circ\text{C}$)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|------------------------------|-----------------------|--|----------|------|------|----------|
| Gate cut-off current | I_{GSS} | $V_{GS} = -30$ V, $V_{DS} = 0$ | — | — | -1.0 | nA |
| Gate-drain breakdown voltage | $V_{(BR) GDS}$ | $V_{DS} = 0$, $I_G = -100$ μA | -40 | — | — | V |
| Drain current | I_{DSS} (Note 1) | $V_{DS} = 10$ V, $V_{GS} = 0$ | 2.6 | — | 20 | mA |
| Gate-source cut-off voltage | $V_{GS (\text{OFF})}$ | $V_{DS} = 10$ V, $I_D = 0.1$ μA | -0.2 | — | -1.5 | V |
| Forward transfer admittance | $ Y_{fs} $ | $V_{DS} = 10$ V, $V_{GS} = 0$, $f = 1$ kHz (Note 2) | 12 | 28 | — | mS |
| Input capacitance | C_{iss} | $V_{DS} = 10$ V, $V_{GS} = 0$, $f = 1$ MHz | — | 30 | — | pF |
| Reverse transfer capacitance | C_{rss} | $V_{DG} = 10$ V, $I_D = 0$, $f = 1$ MHz | — | 6 | — | pF |
| Drain-source ON resistance | $R_{DS (\text{ON})}$ | $V_{DS} = 10$ mV, $V_{GS} = 0$ | (Note 2) | — | 50 | Ω |

Note 1: I_{DSS} classification GR: 2.6~6.5 mA, BL: 6~12 mA, V: 10~20 mANote 2: Condition of the typical value $I_{DSS} = 5$ mA







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